

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
All Times are local time in Berkeley, CA, USA (PDT)									
On June 6-7, 2026 Short Courses are on-line only. From June 8-11, 2026 the workshop is in-person only.									
Version: April 14, 2026 . For questions or comments please contact info@euvlitho.com									
Short Course									
Short Course: EUV and Soft X-Ray Sources									
8:30 AM, Saturday, June 6, 2026, Berkeley, CA (Course is held online Only)									
All Times are for Berkeley, CA, USA. Please estimate times for your own time zones, for this live event.									
Instructors: Gerry O'Sullivan, Marcelo Ackermann, Henry Kapteyn, Dinh Nguyen and Ladislav Pina									
Short Courses and EUVL & Source Workshop require separate registrations. Please visit www.euvlitho.com for information.									
						AV Test and Speaker Check-in	0:15	8:30 AM	8:45 AM
	1		Gerry	O'Sullivan	UCD	Physics of EUV and Short Wavelength Sources with Focus on Atomic Physics	1:30	8:45 AM	10:15 AM
						Break	0:15	10:15 AM	10:30 AM
	2		Marcelo	Ackerman	University of Twente /	EUV Multilayers	1:30	10:30 AM	12:00 PM
						Lunch Break	0:30	12:00 PM	12:30 PM
	3		Henry	Kapteyn	Univ of Colorado and K&M Labs	Fundamentals and Applications of Coherent High Harmonic EUV Sources	1:30	12:30 PM	2:00 PM
						Break	0:15	2:00 PM	2:15 PM
	4		Dinh	Nguyen	xLight	Module 5: FEL for EUV Lithography	1:30	2:15 PM	3:45 PM
						Break	0:15	3:45 PM	4:00 PM
	5		Ladislav	Pina	CTU in Prague	Grazing Incidence Optics and Applications for EUV and Soft X-ray Sources	1:30	4:00 PM	5:30 PM
Short Course Adjourned									

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Short Course									
Short Course: EUV Lithography									
8:30 AM, Sunday, June 7, 2026, Berkeley, CA (Course is held online Only)									
All Times are for Berkeley, CA, USA. Please estimate times for your own time zones, for this live event.									
Instructors: Vivek Bakshi (EUV Litho, Inc.), Sebastian Brueck (Carl Zeiss), Sangsul Lee (Postech University), Patrick Naulleau (EUV Tech), and Jan van Shoot (ASML)									
<i>Short Courses and EUVL & Source Workshop require separate registrations. Please visit www.euvlitho.com for information.</i>									
						AV Test and Speaker Check-in	0:00	8:30 AM	8:30 AM
	1		Vivek	Bakshi	EUV Litho	Introduction to EUVL, EUVL Extension and EUV Sources	1:30	8:30 AM	10:00 AM
						Break	0:15	10:00 AM	10:15 AM
	2		Jan	van Schoot	ASML	High NA EUVL	1:30	10:15 AM	11:45 AM
						Lunch Break	0:30	11:45 AM	12:15 PM
	3		Patrick	Naulleau	EUV Tech	EUVL Imaging and Patterning	1:30	12:15 PM	1:45 PM
						Break	0:15	1:45 PM	2:00 PM
	4		Sebastian	Brueck	Carl Zeiss	EUVL Optics	1:15	2:00 PM	3:15 PM
						Break	0:15	3:15 PM	3:30 PM
	5		Sangsul	Lee	Postech	EUVL Masks	1:30	3:30 PM	5:00 PM
Short Course Adjourned									

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Day 1 (AM): Blue-X Technical Working Group (TWG) Meeting									
<i>In-person Meeting, Open to Blue-X TWG Members only</i>									
8:30 AM - 5:00 PM , Monday, June 8, 2026, Pauley Ballroom, UC Berkeley, CA									

Breakfast, Coffee and Check-in

0:30 8:00 AM 8:30 AM

Technical Working Group Discussions and Blue-X TWG Member Presentations 9:30 AM - 4:00 PM

Session 1: Blue-X Opening Session. Session Chair: Allen Gabor (IBM)

1	Intro-1	Blue-X TWG	Vivek	Bakshi	EUV Litho	Announcements	0:05	8:30 AM	8:35 AM
1	B1	Blue-X TWG	Vivek	Bakshi	EUV Litho	Blue-X TWG: Status and Plans	0:15	8:35 AM	8:50 AM

Session 2: Blue-X Keynote, Session Chair: Allen Gabor (IBM)

2	B4	Blue-X Keynote	Takeo	Watanabe	University of Hyogo	The Lithographic Benefit and Technical Issue of Shortening the Wavelength of EUVL	0:30	8:50 AM	9:20 AM
2	B1	Blue-X Keynote	Ralph	Dammel	Merck / EMD Electronics	Dose Requirements for LCDU Control at Blue-X Wavelengths	0:30	9:20 AM	9:50 AM
2	B3	Blue-X Keynote	Yuri	Ralchenko	UMD	Overview of Atomic Spectroscopic Data for the Blue-X Water Window Program	0:30	9:50 AM	10:20 AM
2	B2	Blue-X Keynote	Vladimir	Lieberman	MIT LL	Robust Design and Material Optimization for Multilayer Coatings for Blue-X Wavelengths	0:30	10:20 AM	10:50 AM
Break							0:15	10:50 AM	11:05 AM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Monday, June 8, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 3: Blue-X-Optics, Session Co-Chairs: TBA									
3	B46	Blue-X-Optics	Antonio	Checco	Veeco	Blue-X ML Optics Sub - TWG Update	0:10	11:05 AM	11:15 AM
3	B45	Blue-X-Optics	Marcelo	Ackermann	University of Twente	TBA	0:15	11:15 AM	11:30 AM
3	B43	Blue-X-Optics	Naoki	Hayase	University of Hyogo	Improved Mo2N/B multilayer for beyond EUV lithography	0:15	11:30 AM	11:45 AM
3	B44	Blue-X-Optics	Takeo	Ejima	Tohoku University (SRIS)	Deposition System for Reflective Multilayers Below 6.x nm Enabled by Sub-nm Thickness Control	0:15	11:45 AM	12:00 PM
3	B41	Blue-X-Optics	Eric	Gullikson	LBNL	ML Project Update (Tentative Title)	0:15	12:00 PM	12:15 PM
3	B42	Blue-X-Optics	Ladislav	Pina	Rigaku	Grazing Incidence Mirror for FEL Water Window Beams	0:15	12:15 PM	12:30 PM
Lunch							1:00	12:30 PM	1:30 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Monday, June 8, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 4: Source Sub-TWG, Session Co-Chairs: TBA									
4	B67	Blue-X-Source	TBA			Blue-X Plasma Sources Sub - TWG Update	0:10	1:30 PM	1:40 PM
4	B63	Blue-X-Source	Yusuke	Teramoto	Ushio	Short-Wavelength Radiation from a Regenerative Target Laser-Produced Plasma Source	0:15	1:40 PM	1:55 PM
4	B66	Blue-X-Sources	Mariko	Yamaguchi	RIC	Laser-Driven, High Brilliance Sources in the BEUV to Tender X-ray Range	0:15	1:55 PM	2:10 PM
4	B65	Blue-X-Source	Tommy	Sebastian	MIT LL	Development and Testing of Liquid Nitrogen Droplet Generator	0:15	2:10 PM	2:25 PM
4	B61	Blue-X-Source	Yosuke	Honda	KEK	FEL Development Status Update	0:15	2:25 PM	2:40 PM
4	B64	Blue-X-Source	Brandon	Holybee	xLight	Impact of EUV FEL Exposure on Photoresist Sensitivity and Chemical Mechanisms	0:15	2:40 PM	2:55 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Monday, June 8, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 5: Blue-X Mask, Session Co-Chairs: TBA									
							0:10	2:55 PM	3:05 PM
5	B21	Blue-X-Mask	Meng / Ben	Lee / Eynon	Veeco / Lam	Blue-X Mask Sub - TWG Update			
5	B22	Blue-X-Mask	Marcus	Benk	CXRO	SHARP Photomask Imaging: Supporting the Extension of EUV Lithography Beyond 0.55NA and 13.5nm Wavelength	0:15	3:05 PM	3:20 PM
Break							0:15	3:20 PM	3:35 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Monday, June 8, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 6: Blue-X Metrology, Session Co-Chairs: TBA									
6	B32	Blue-X-Metrology	TBA			Blue-X ML Optics Sub - TWG Update	0:10	3:35 PM	3:45 PM
6	P33	Blue-X-Metrology	Victor	Soltwisch	PTB	Infrastructure for the Water Window: Status and Future of Optical Metrology	0:15	3:45 PM	4:00 PM
6	B31	Blue-X-Metrology	Ben	Zeiger	Luxel	Transmission Filters for <13.5 nm Lithography	0:15	4:00 PM	4:15 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Monday, June 8, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 7: Blue-X Resist, Session Co-Chairs: TBA									
7	B52	Blue-X - Resist and Patterning	TBA			Blue-X Resist Sub - TWG Update	0:10	4:15 PM	4:25 PM
7	B51	Blue-X - Resist and Patterning	Dario	Goldfarb	IBM	Interactions of Polarized EUV Light with Resist	0:15	4:25 PM	4:40 PM
							0:20	4:40 PM	5:00 PM
							Break		
							1:00	5:00 PM	6:00 PM
Joint Reception with 2026 EUVL and Source Workshop Attendees / Registration									
Blue-X TWG Meeting Adjourned									

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Day 1 (PM): 2026 EUVL and Source Workshop									
Joint Reception: Blue- X TWG and 2026 EUVL and Source Workshop									
Monday, June 8, 2026, Pauley Ballroom, UC Berkeley, CA									
Registration and Reception							1:00	5:00 PM	6:00 PM
Joint Reception Adjourned									

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Day 2: 2026 EUVL and Source Workshop									
8:30 AM - 7:00 PM, Tuesday, June 9, 2026, Pauley Ballroom, UC Berkeley, CA									
<i>Please see Abstract Book on website www.euvlitho.com for abstracts and co-author(s) information by paper #.</i>									
Session 1: Keynote-1, Session Chair: Patrick Naulleau (EUV Tech)									
						<i>Breakfast, Coffee and Check-in</i>	0:30	8:30 AM	9:00 AM
		Intro-2	Vivek Bakshi		EUV Litho	Welcome and Announcements	0:10	9:00 AM	9:10 AM
1	P1	Keynote -1	Allen	Gabor	IBM	Beyond High-NA EUV: A Dose-Window Framework for Stochastic Integrity at Future Nodes	0:30	9:10 AM	9:40 AM
1	P2	Keynote -1	Vineet	Vijayakrishnan Nair	Micron	Mask Wafer Co Optimization for High NA EUV Readiness in Advanced DRAM	0:30	9:40 AM	10:10 AM
							0:20	10:10 AM	10:30 AM
Break									

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Tuesday, June 9, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 2: Source - 1, Session Co-Chairs: TBA									
							0:15	10:30 AM	10:45 AM
2	P76	Source -1	Oscar	Versolato	ARCNL	TBA			
2	P74	Source -1	Hakaru	Mizoguchi	Kyushu university	EUV Exposure for Photo-Chemical Materials and LPP-EUV Source Research for Semiconductor Manufacturing II	0:15	10:45 AM	11:00 AM
2	P78	Source -1	Arun	Devaraj	PNNL	Accelerating Next-Generation EUV Lithography (ANGEL) through a Co-Design of Laser-Produced Plasma Sources and Multilayer Mirrors	0:15	11:00 AM	11:15 AM
2	P77	Source -1	Kentaro	Tomita	Hokkaido University	Control of the Ion Energy Distribution Function in Double-Pulse Laser-Produced EUV Plasmas	0:15	11:15 AM	11:30 AM
2	P75	Source -1	Tirtha	Joshi	UCSD	Scaling of EUV Conversion Efficiency with Material and Laser Intensity in High-Z Plasmas	0:15	11:30 AM	11:45 AM
2	P71	Source -1	Mats	Brinkman	ARCNL	Broadband EUV Imaging Spectrometry	0:15	11:45 AM	12:00 PM
2	P79	Source -1	Owen	Bardeen	UC San Diego	Pulse Conditioning and Material Comparisons for Optimized EUV and Beyond-EUV Emission from Laser-Produced Plasmas	0:15	12:00 PM	12:15 PM
Lunch							1:00	12:15 PM	1:15 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Tuesday, June 9, 2026, Pauley Ballroom, UC Berkeley, CA									
<i>Session 3: Source - 2, Session Co-Chairs: TBA</i>									
3	P72	Source -2	David	Reisman	Energetiq	EQS-10: A Next-Generation DPP EUV Light Source	0:15	1:15 PM	1:30 PM
3	P73	Source -2	Tomoyoshi	Toida	Gigaphoton	Development of Sn-LPP EUV Light Source for Actinic Mask Inspection	0:15	1:30 PM	1:45 PM
3	P80	Source -2	Hideyuki	Sera	Ushio	Comparative Collective Thomson Scattering Study of Single and Dual-Trigger LDP Tin Plasmas in an EUV Source	0:15	1:45 PM	2:00 PM
Break							0:15	2:00 PM	2:15 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Tuesday, June 9, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 4: Resist and Patterning -1, Session Co-Chairs: TBA									
4	P47	Resist and Patterning -1	Anuja	De Silva	Lam	Dry Patterning Solutions Enabling High NA Lithography for Accelerated Feature Scaling	0:15	2:15 PM	2:30 PM
4	P53	Resist and Patterning -1	Stacey	Bent	Stanford	Molecular Layer Deposition of Metal Coordination Polymer Resists for EUV Lithography	0:15	2:30 PM	2:45 PM
4	P52	Resist and Patterning -1	Satinder	Sharma	SCEE/SCS	Iodine Functionalized Metal-Organic Cluster EUV Resists for High-Resolution Patterning with Fab-Compatible Processing	0:15	2:45 PM	3:00 PM
4	P51	Resist and Patterning -1	Iacopo	Mochi	PSI	Interference Lithography at EUV and Beyond at the XIL-II beamline	0:15	3:00 PM	3:15 PM
4	P50	Resist and Patterning -1	Ryan	Miyakawa	LBNL	Supporting Next-Gen EUVL: Hyper-NA and BEUV at CXRO	0:15	3:15 PM	3:30 PM
Break							0:15	3:30 PM	3:45 PM

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Tuesday, June 9, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 5: Supplier Showcase, Session Co-Chairs: TBA									
5	P95	Supplier Showcase	Analía	Herrero	PTB	Soft X-rays for the Inspection of Complex Nanostructures and Thin-layers	0:15	3:45 PM	4:00 PM
5	P93	Supplier Showcase	Jacqueline	van Veldhoven	TNO	EUV-Generated Plasma Characterization Using a Transparent RFEA	0:15	4:00 PM	4:15 PM
5	P94	Supplier Showcase	Meng	Lee	Veeco	TBA	0:15	4:15 PM	4:30 PM
5	P92	Supplier Showcase	Henry	Chou	Energetiq	TBA	0:15	4:30 PM	4:45 PM
5	P91	Supplier Showcase	Matt	Hettermann	EUV Tech	Applications of EUV Metrology Tools	0:15	4:45 PM	5:00 PM
Break							0:30	5:00 PM	5:30 PM

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Tuesday, June 9, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 6: Poster Session, Session Chair: Vivek Bakshi (EUV Litho)									
							1:30	5:30 PM	7:00 PM
						Poster Session and Reception			
6	P101	Poster-Optics	Akira	Miyake	Toyama	The Development of EUV and Soft X-ray Optical Evaluation Systems in TOYAMA			
6	P102	Poster-Resist and Patterning	Gahyun	Lee	Chonnam National University	T4(THP)4: Exploring Silicon-Based Inorganic Molecular Resists for Blue-X (6.7 nm) Lithography			
6	P103	Poster-Resist and Patterning	Hayun	Kim	Chonnam National University	Dynamic Covalent Assembly(DCA)-Zinc Oxo Cluster Resists for EUV, Blue-X (6.7 nm) and Blue-X (3.1 nm) Lithography			
6	P104	Poster-Resist and Patterning	Seungyong	Baek	Chonnam National University	Synthetic and Process Optimization of the Tin-Oxo Cluster CNU-TOC-01 toward Improved EUV Lithographic Performance			
6	P105	Poster-Resist and Patterning	Hyun-Sung	Yoon	Chonnam National University	CASILON: A Core-Arm Siloxane Molecular Resist Candidate for Blue-X (6.7 nm) Lithography			
6	P106	Poster-Resist and Patterning	Kenneth	Gonsalves	Indian Institute of Technology	Photoresists Beyond EUV: Revisiting X-ray Nanocomposite Resists - For Potential BEUVL			
6	P107	Poster-Source	Wooram	Kim	Korea Research Institute of Standards and Science	Tabletop Extreme Ultraviolet (EUV) Testing Platform for Lithography Materials			
6	P108	Poster-Source	Kyu Chang	Park	Kyung Hee University	Performance of EUV Light Source with Cold Field Emitters (CFEs) Beam Irradiation Technique			

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6	P109	Poster-Source	Matthew	Polek	PNNL	Dynamics of pre-pulsed laser-produced plasmas generated using mass limited Sn targets			
6	P110	Poster-Source	Stanislav	Musikhin	PPPL	Multi-diagnostic experimental characterization of laser-produced tin plasmas			
6	P111	Poster-Optics	Masatoshi	Hatayama	NTT	Development and Evaluation of Free-standing Mo/Si Multilayer Beam Splitters			
6	P112	Poster - Metrology	TBA		Inprentus	Maximize EUV and BEUV Instrument Performance with Custom Blazed, Variable-Line-Space Reflection Gratings on Flat or Curved Surfaces			

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Day 3: 2026 EUVL and Source Workshop									
8:30 AM - 4:30 PM, Wednesday, June 10, 2026, Pauley Ballroom, UC Berkeley, CA									
<i>Session 7: Keynote - 2, Session Chair: Ricardo Ruiz (LBNL)</i>									
							0:30	8:30 AM	9:00 AM
<i>Breakfast, Coffee and Check-in</i>									
		Intro-3	Vivek Bakshi		EUV Litho	Welcome and Announcements	0:10	9:00 AM	9:10 AM
7	P3	Keynote -2	Ronald	Goossens	ASML	The Amazing Longevity of Moore’s Law - 50 Years of Progress in Lithography	0:30	9:10 AM	9:40 AM
7	P4	Keynote -2	Laura	Waller	UC Berkeley /BETR Center	Computational Microscopy for EUV Lithography	0:30	9:40 AM	10:10 AM
Break							0:20	10:10 AM	10:30 AM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Wednesday, June 10, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 8: Optics, Mask and Mask Metrology, Session Co-Chairs: TBA									
8	P26	Optics, Mask and Mask Metrology	Sebastian	Brueck	Carl Zeiss	Advancements in ZEISS EUV Projection Optics: Enhancing Productivity and Enabling Shrink	0:15	10:30 AM	10:45 AM
8	P23	Optics, Mask and Mask Metrology	Binyamin	Rubin	Veeco	In Situ Monitoring During Mo-Si Multilayer Deposition for EUV Mask Blanks : Concept and Simulation	0:15	10:45 AM	11:00 AM
8	P21	Optics, Mask and Mask Metrology	Ayumi	Moriya	Hoya	Development of Capping Films Integrated with Mask Process for 1.X nm Node EUV Blanks	0:15	11:00 AM	11:15 AM
8	P24	Optics, Mask and Mask Metrology	Stuart	Sherwin	EUV Tech	Harnessing the Power of Actinic Metrology for EUV Masks	0:15	11:15 AM	11:30 AM
8	P25	Optics, Mask and Mask Metrology	Luke	Long	EUV Tech	TBA	0:15	11:30 AM	11:45 AM
8	P22	Optics, Mask and Mask Metrology	Zachary	Levinson	Synopsys	Accurate Long Range Compact Modeling for Low-NA and High-NA EUV Mask Solutions	0:15	11:45 AM	12:00 PM
8	P27	Optics, Mask and Mask Metrology	Dong Gun	Lee	E-Sol	Integrated Actinic EUV Tool for Mask Review, Reflectometry, High-speed CD, and Phase Measurement	0:15	12:00 PM	12:15 PM
Lunch							1:00	12:15 PM	1:15 PM

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Wednesday, June 10, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 9: Metrology, Session Co-Chairs: TBA									
9	P34	Metrology	Ahmed	Diallo	PPPL	SparkLight: A New Platform for Laser-Produced Plasma Research in Support of Next-Generation EUV Lithography	0:15	1:15 PM	1:30 PM
9	P31	Metrology	Stephanie	Moffitt	NIST	New Developments at the Synchrotron Ultraviolet Radiation Facility (SURF III)	0:15	1:30 PM	1:45 PM
9	P32	Metrology	Brian	Simonds	NIST	Progress on the NIST Deployable Absolute EUV Radiometer	0:15	1:45 PM	2:00 PM
9	P33	Metrology	Jiho	Kim	Pohang/POST ECH	Actinic EUV/Blue-X Characterization for Advanced Materials and Lithography Applications	0:15	2:00 PM	2:15 PM
Break							0:15	2:15 PM	2:30 PM

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Wednesday, June 10, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 10: Sources Modeling, Session Co-Chairs: TBA									
10	P85	Source - Modeling	Igor	Golovkin	Prism Computations	Atomic Data and Collisional-Radiative Atomic Kinetics Simulations for EUV/x-ray Sources	0:15	2:30 PM	2:45 PM
10	P81	Source - Modeling	John	Sheil	ARCNL	TBA	0:15	2:45 PM	3:00 PM
10	P82	Source - Modeling	James	Colgan	LANL	Effective Temperature Approximations for Use in Modeling Non-LTE Tin Plasmas	0:15	3:00 PM	3:15 PM
10	P83	Source - Modeling	Mark	Sherlock	LLNL	Quantum Effects in the Absorption of Laser Light by EUV-Source Relevant Plasmas	0:15	3:00 PM	3:15 PM
10	P84	Source - Modeling	Kirill	Lezhnin	PPPL	Simulating Fast Ion Debris for Next-Generation Light Sources for Nanolithography	0:15	3:15 PM	3:30 PM
10	P86	Source - Modeling	Akira	Sasaki	QST	Investigation of Atomic Processes and Radiative Transfer in Tin Plasmas for Updating the Opacity Table	0:15	3:15 PM	3:30 PM
10	P87	Source - Modeling	Nozomi	Tanaka	University of Osaka	Optimization of EUV Output by Experimentally Validated Radiation-Hydrodynamic Simulations Across a Broad Laser Parameter Space	0:15	3:30 PM	3:45 PM
Break							0:45	3:45 PM	4:30 PM
UC Berkeley Campus Walking Tour							1:00	4:30 PM	5:30 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Day 4: 2026 EUVL and Source Workshop									
9:30 AM - 4:30 PM, Thursday, June 11, 2026, Pauley Ballroom, UC Berkeley, CA									
Session 11: Lasers, Session Chair: TBA									
Breakfast, Coffee and Check-in							0:30	9:30 AM	10:00 AM
		Intro-4	Vivek Bakshi		EUV Litho	Welcome and Announcements	0:05	10:00 AM	10:05 AM
11	P14	Lasers	Jens	Brunne	Trumpf	Scaling Efficiency and Power in CO ₂ Drive Lasers for EUV	0:15	10:05 AM	10:20 AM
11	P16	Lasers	Emily	Sistrunk Link	LLNL	High Energy Solid-State $\lambda \approx 2 \mu\text{m}$ Laser Drivers for Efficient EUV and Plasma Sources	0:15	10:20 AM	10:35 AM
11	P11	Lasers	Tobias	Heuermann	AFS	2 μm Fiber Lasers as Efficient Next Generation EUV Drive Lasers	0:15	10:35 AM	10:50 AM
11	P15	Lasers	Joachim	Gräfe	Trumpf	A Scalable 2 μm Laser Platform for Next Generation EUV Light Sources	0:15	10:50 AM	11:05 AM
11	P13	Lasers	Ryo	Yasuhara	National Institute for Fusion	Development of a High-Power 3–4 μm Mid-Infrared Laser for High-Efficiency EUV Light Sources	0:15	11:05 AM	11:20 AM
11	P12	Lasers	Robert	Klas	Fraunhofer IOF	Power Scalable Highly Efficient High Harmonic Generation at 13.5 nm Using a Visible-Driving Laser	0:15	11:20 AM	11:35 AM
Break							0:15	10:35 AM	10:50 AM

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Thursday, June 11, 2026, Pauley Ballroom, UC Berkeley									
Session 12: Laser Wakefield Accelerator (LWFA), Session Co-Chairs: TBA									
12	P17	Laser Wakefield Accelerator	Finn	Kohrell	LBNL	Compact Free-Electron Lasing at BELLA Center's Laser-Plasma Accelerator	0:15	10:50 AM	11:05 AM
12	P18	Laser Wakefield Accelerator	Manuel	Kirchen	Deutsches Elektronen-Synchrotron	Laser-Plasma Accelerators and Their Potential to Drive EUV Light Sources	0:15	11:05 AM	11:20 AM
12	P19	Laser Wakefield Accelerator	Stephen	Milton	TAU Systems	TAU Systems Inc.: Bringing Laser-Powered Accelerator Systems to the Commercial Market	0:15	11:20 AM	11:35 AM
12	P20	Laser Wakefield Accelerator			TBA	TBA	0:15	11:35 AM	11:50 AM
Lunch							1:10	11:50 AM	1:00 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Thursday, June 11, 2026, Pauley Ballroom, UC Berkeley									
Session 13: Resist and Patterning 2, Session Co-chairs: TBA									
13	P55	Resist and Patterning -2	Takahiro	Kozawa	University of Osaka	Development of Resist Materials under JST K Program	0:15	1:00 PM	1:15 PM
13	P42	Resist and Patterning -2	Chang-Yong	Nam	Brookhaven National Lab	EUV Research Activities and Infrastructure Development at BNL (Invited)	0:15	1:15 PM	1:30 PM
13	P48	Resist and Patterning -2	Ricardo	Ruiz	LBNL	Navigating Chemical Stochasticity in EUV Lithography: CHIPPS Materials Platforms and Metrology	0:15	1:30 PM	1:45 PM
Break							0:15	1:45 PM	2:00 PM

#	Paper #	Area	Presenter (First)	Presenter (Last)	Company	Title	Duration	Start	Finish
Thursday, June 11, 2026, Pauley Ballroom, UC Berkeley									
Session 14: Resist and Patterning -3 , Session Co-chairs: TBA									
14	P46	Resist and Patterning -3	Michael	Tsapatsis	John Hopkins University	Amorphous Zeolitic Imidazolate Frameworks (aZIF) as Resists for EUV and BEUV Lithography	0:15	2:00 PM	2:15 PM
14	P54	Resist and Patterning -3	Congque	Dinh	TEL	Holistic Integration of Novel Patterning Technologies for High-NA EUV Lithography	0:15	2:15 PM	2:30 PM
14	P49	Resist and Patterning -3	Samuel	Blau	LBNL	Discovering EUV Photoresist Chemistry through Automated Reaction Network Construction and Spatiotemporal Kinetic Simulation	0:15	2:30 PM	2:45 PM
14	P56	Resist and Patterning -3	Kyunghyeon	Lee	University of Chicago	Design of block copolymers for directed self-assembly to mitigate stochastic challenges in EUV lithography	0:15	2:45 PM	3:00 PM
14	P45	Resist and Patterning -3	Jiwon	Kim	Hanyang Univ/CH3IPS	Defect-Free EUV Patterning of Metal Oxide Resists using Cl ₂ /Ar LET Plasma Dry Development for High-Fidelity Etch Transfer	0:15	3:00 PM	3:15 PM
14	P57	Resist and Patterning -3	Jiyong	Kim	UT Dallas	Dry Developing Process of Molecular-Atomic-Layer-Deposited Hybrid Dry Photoresist for EUV Lithography	0:15	3:15 PM	3:30 PM
14	P41	Resist and Patterning -3	Nikhil	Tiwale	BNL	Positive-Tone Hybrid EUV Resists Synthesized by Vapor Phase Infiltration	0:15	3:30 PM	3:45 PM
						Announcements	0:15	3:45 PM	4:00 PM
						Break	0:30	4:00 PM	4:30 PM
						Buses Depart for Dinner Cruise		4:30 PM	
						Workshop Dinner Cruise	3:30	5:30 PM	9:00 PM
Workshop Adjourned									